

MOS FIELD EFFECT TRANSISTOR

3SK134B

RF AMP. FOR UHF TV TUNER N-CHANNEL SILICON DUAL GATE MOS FIELD-EFFECT TRANSISTOR 4 PINS MINI MOLD

FEATURES

• High Power Gain : $G_{ps} = 23.0 \text{ dB TYP.}$ (@ = 900 MHz)

• Low Noise Figure : NF = 2.4 dB TYP. (@ = 900 MHz)

• Suitable for use as RF amplifier in UHF TV tuner.

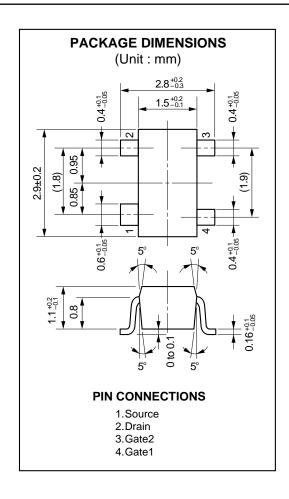
· Automatically Mounting: Embossed Type Taping

• Surface Mount Package: 4 Pins Mini Mold (EIAJ: SC-61)

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C)

Drain to Source Voltage	VDSX	18	V
Gate1 to Source Voltage	V _{G1} S	±8 (±10)* 1	V
Gate2 to Source Voltage	V _{G2} S	±8 (±10)*1	V
Gate1 to Drain Voltage	V_{G1D}	18	V
Gate2 to Drain Voltage	V_{G2D}	18	V
Drain Current	ΙD	25	mΑ
Total Power Dissipation	Po	200	mW
Channel Temperature	T_ch	125	°C
Storage Temperature	T_{stg}	-55 to +125	°C

*1 : $R_L \ge 10 \text{ k}\Omega$



PRECAUTION:

Avoid high static voltages or electric fields so that this device would not suffer from any damage due to those voltage fields.



ELECTRICAL CHARACTERISTICS (TA = 25 $^{\circ}$ C)

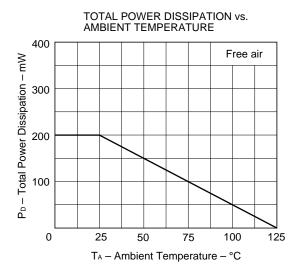
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source Breakdown Voltage	BV _{DSX}	18			V	$V_{G1S} = V_{G2S} = -2 \text{ V}, \text{ ID} = 10 \mu\text{A}$
Drain Current	losx	0.4		8.0	mA	VDS = 10 V, VG2S = 4 V, VG1S = 0.5 V
Gate1 to Source Cutoff Voltage	V _{G1S(off)}			-2.0	V	$V_{DS} = 10 \text{ V}, V_{G2S} = 4 \text{ V}, I_{D} = 10 \mu A$
Gate2 to Source Cutoff Voltage	VG2SS(off)			-0.7	V	$V_{DS} = 10 \text{ V}, V_{G1S} = 4 \text{ V}, I_{D} = 10 \mu A$
Gate1 Reverse Current	I _{G1SS}			±20	nA	VDS = VG2S = 0, VG1S = ±8 V
Gate2 Reverse Current	I _{G2} ss			±20	nA	VDS = VG1S = 0, VG2S = ±8 V
Forward Transfer Admittance	yfs	25.0	29.0	35.0	mS	V _{DS} = 10 V, V _{G2S} = 4 V, I _D = 10 mA f = 1 kHz
Input Capacitance	Ciss	1.5	2.5	3.5	pF	V _{DS} = 10 V, V _{G2S} = 4 V, I _D = 10 mA f = 1 MHz
Output Capacitance	Coss	0.6	1.1	1.6	pF	
Reverse Transfer Capacitance	Crss		0.02	0.03	pF	
Power Gain	Gps	20.0	23.0		dB	V _{DS} = 10 V, V _{G2S} = 4 V, I _D = 10 mA f = 900 MHz
Noise Figure	NF		2.4	3.5	dB	

IDSX Classification

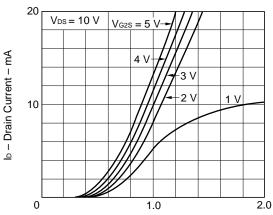
Rank	U55/UEE	U56/UEF
Marking	U55	U56
Idsx (mA)	0.4 to 5.0	3.0 to 8.0

2

TYPICAL CHARACTERISTICS (TA = 25 °C)

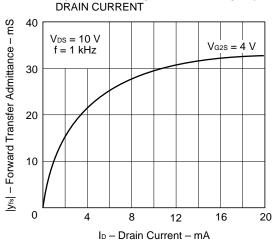




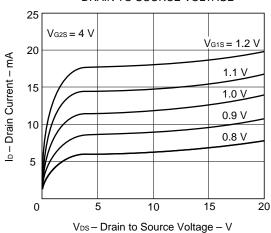


FORWARD TRANSFER ADMITTANCE vs.

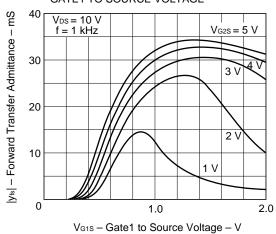
V_{G1S} - Gate1 to Source Voltage - V



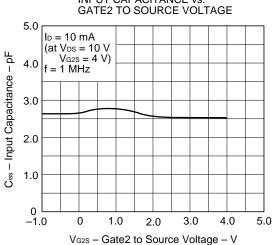
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



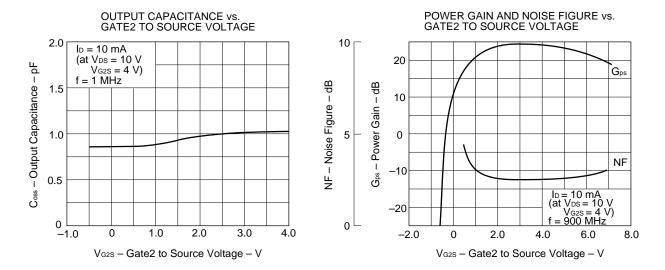
FORWARD TRANSFER ADMITTANCE vs. GATE1 TO SOURCE VOLTAGE



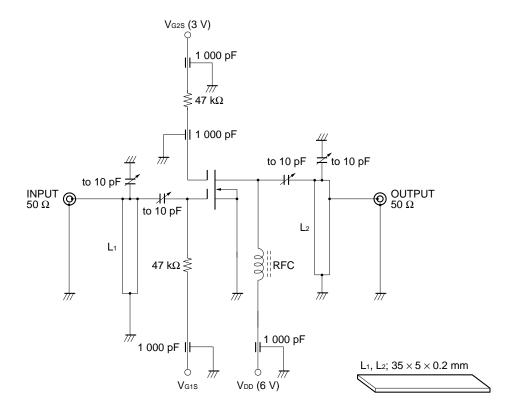
INPUT CAPACITANCE vs.







900 MHz Gps AND NF TEST CIRCUIT



4

No part of this document may be copied or reproduced in any form or by any means without the prior written consent of NEC Corporation. NEC Corporation assumes no responsibility for any errors which may appear in this document.

NEC Corporation does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from use of a device described herein or any other liability arising from use of such device. No license, either express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Corporation or others.

While NEC Corporation has been making continuous effort to enhance the reliability of its semiconductor devices, the possibility of defects cannot be eliminated entirely. To minimize risks of damage or injury to persons or property arising from a defect in an NEC semiconductor device, customer must incorporate sufficient safety measures in its design, such as redundancy, fire-containment, and anti-failure features.

NEC devices are classified into the following three quality grades:

"Standard", "Special", and "Specific". The Specific quality grade applies only to devices developed based on a customer designated "quality assurance program" for a specific application. The recommended applications of a device depend on its quality grade, as indicated below. Customers must check the quality grade of each device before using it in a particular application.

Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

The quality grade of NEC devices in "Standard" unless otherwise specified in NEC's Data Sheets or Data Books. If customers intend to use NEC devices for applications other than those specified for Standard quality grade, they should contact NEC Sales Representative in advance.

Anti-radioactive design is not implemented in this product.